DATA SHEET



SILICON POWER TRANSISTOR 288601

PNP SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR LOW-FREQUENCY POWER AMPLIFIERS AND LOW-SPEED SWITCHING

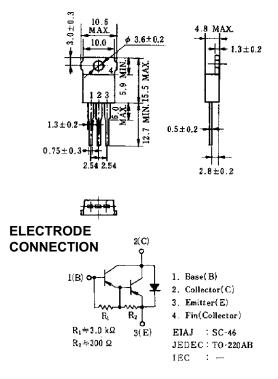
FEATURES

- · High-DC current gain due to Darlington connection
- · Low collector saturation voltage
- Low collector cutoff current
- Ideal for use in direct drive from IC output for magnet drivers such as treminal equipment or cash registers

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	-100	V
Collector to emitter voltage	VCEO	-100	V
Emitter to base voltage	Vebo	-7.0	V
Collector current	IC(DC)	∓5.0	А
Collector current	IC(pulse)*	∓8.0	А
Base current	B(DC)	-0.5	А
Total power dissipation	P⊤ (Ta = 25°C)	1.5	W
Total power dissipation	P⊤ (Tc = 25°C)	30	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

PACKAGE DRAWING (UNIT: mm)



* PW \leq 10 ms, duty cycle \leq 50%

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

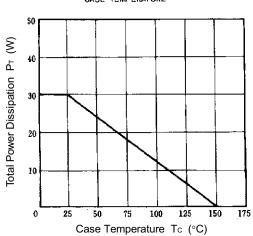
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = –3 A, Iв1 = –3 mA, L = 1 mH –100				V
Collector to emitter voltage	VCEX(SUS)1					V
Collector to emitter voltage	VCEX(SUS)2	$\label{eq:lc} \begin{array}{l} I_{C} = -6 \mbox{ A}, I_{B1} = -12 \mbox{ mA}, I_{B2} = 3 \mbox{ mA}, \\ V_{BE(OFF)} = 5.0 \mbox{ V}, \mbox{ L} = 180 \mu \mbox{ H}, \mbox{ clamped} \end{array}$	-100			V
Collector cutoff current	Ісво	$V_{CB} = -100 \text{ V}, \text{ I}_{E} = 0$			-10	μA
Collector cutoff current	ICER	$V_{CE} = -100 \text{ V}, \text{ R}_{BE} = 51 \Omega, \text{ Ta} = 125^{\circ}\text{C}$			-1.0	mA
Collector cutoff current	ICEX1	$V_{\text{CE}} = -100 \text{ V}, \text{ V}_{\text{BE(OFF)}} = 1.5 \text{ V}$			-10	μA
Collector cutoff current	ICEX2	$\label{eq:Vce} \begin{array}{l} V_{\text{CE}} = -100 \text{ V}, V_{\text{BE}(\text{OFF})} = 1.5 \text{ V}, \\ Ta = 125^{\circ}\text{C} \end{array}$			-1.0	mA
Emitter cutoff current	Іево	V _{EB} = -5.0 V, Ic = 0			-3.0	mA
DC current gain	hfe1*	Vce = -2.0 V, Ic = -3.0 A	2,000		15,000	
DC current gain	hfe2*	Vce = -2.0 V, Ic = -5.0 A	500			
Collector saturation voltage	V _{CE(sat)} *	Ic = -3.0 A, I _B = -3.0 mA			-1.5	V
Base saturation voltage	V _{BE(sat)} *	Ic = -3.0 A, I _B = -3.0 mA			-2.0	V
Turn-on time	ton	lc = −3.0 A, R∟ = 17 Ω,		0.5		μs
Storage time	tstg	$I_{B1} = -I_{B2} = -3.0 \text{ mA}, \text{ Vcc} \cong -50 \text{ V}$ Refer to the test circuit.		1.0		μs
Fall time	tr			1.0		μs

* Pulse test PW \leq 350 μ s, duty cycle \leq 2%

hFE CLASSIFICATION

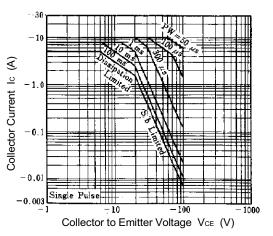
Marking	М	L	К
hfe1	2,000 to 5,000	3,000 to 7,000	5,000 to 15,000

TYPICAL CHARACTERISTICS (Ta = 25°C)

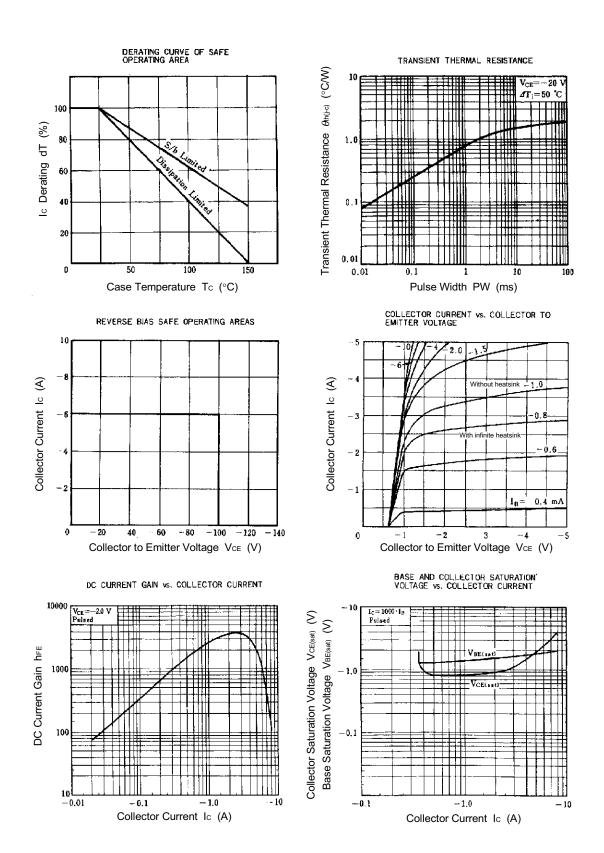




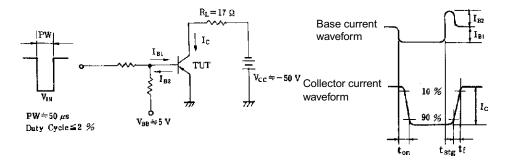
SAFE OPERATING AREAS







SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT



[MEMO]

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